

Low Voltage Single N-Channel MOSEFT

Part Number	Package	Availability	Drain-Source Voltage V_{DS} (V)	Rdson Max@ $V_{GS} =$ (mohm)			Continuous Drain Current I_D (A)	Total Gate Charge Q_g (nC) $V_{GS} = 10V$	Power Dissipation P_D (W)
				10V	4.5V	2.5V			
				PFD3000	TO-252	Now			
PFU3000	TO-251	Now	30	12.5	--	--	50	35	52
PFS3000	TO-263	Now	30	12.5	--	--	50	35	52
PFE3000	SO-8	September 04	30	TBD	--	--	TBD	TBD	TBD
PFD3002	TO-252	Now	30	8.0	--	--	71	62.5	83
PFU3002	TO-251	Now	30	8.0	--	--	71	62.5	83
PFS3002	TO-263	August 04	30	8.0	--	--	71	62.5	83
PFE3002	SO-8	August 04	30	TBD	--	--	TBD	TBD	TBD
PFD3004	TO-252	Now	30	6.0	--	--	107	98.3	119
PFU3004	TO-251	Now	30	6.0	--	--	107	98.3	119
PFS3004	TO-263	Now	30	5.5	--	--	107	98.3	119
PFD3010	TO-252	Now	30	14	--	--	46	35	52
PFU3010	TO-251	Now	30	14	--	--	46	35	52
PFS3010	TO-263	Now	30	14	--	--	46	35	52
PFE3010	SO-8	September 04	30	TBD	--	--	TBD	TBD	TBD
PFB3014	TO-220	October 04	30	4.0	--	--	TBD	TBD	TBD
PFB6000	TO-220	Now	60	18	--	--	59	37.7	150

Low Voltage Dual N-Channel MOSEFT

Part Number	Package	Availability	Drain-Source Voltage V_{DS} (V)	Rdson Max@ $V_{GS} =$ (mohm)			Continuous Drain Current I_D (A)	Total Gate Charge Q_g (nC) $V_{GS} = 10V$	Power Dissipation P_D (W)
				10V	4.5V	2.5V			
				PFE4200	SO-8	August 04			
PFE5200	SO-8	August 04	45	30	34	--	TBD	TBD	TBD

Low Voltage Single P-Channel MOSEFT

Part Number	Package	Availability	Drain-Source Voltage V_{DS} (V)	Rdson Max@ $V_{GS} =$ (mohm)			Continuous Drain Current I_D (A)	Total Gate Charge Q_g (nC) $V_{GS} = 10V$	Power Dissipation P_D (W)
				10V	4.5V	2.5V			
				PFE3001	SO-8	September 04			

联系地址：深圳市深南中路福田大厦西 1209 室

联系电话：0755-83692325, 83692353

网址：www.szxinuo.com 深圳市心诺微电子有限公司